

HAC RF Emissions Test Report

Test report no.:	RF_RM-634_01	Date of report:	2010-05-27
Template version:	7.0	Number of pages:	31
Testing laboratory:	TCC Nokia Salo Laboratory P.O.Box 86 Joensuunkatu 7H / Kiila 1B FIN-24101 SALO, FINLAND Tel. +358 (0) 7180 08000 Fax. +358 (0) 7180 45220	Client:	Nokia Corporation Frederikskaj 1790 COPENHAGEN V DENMARK Tel. +45 33 292929 Fax. +45 33 292934
Responsible test engineer:	Heikki Kuusela	Product contact person:	Shao Xu
Measurements made by:	Heikki Kuusela, Janne Hirsimäki		
Tested devices:	RM-634		
FCC ID:	QTKRM-634	IC:	661AD-RM634
Supplement reports:	T-Coil_RM-634_02, RF_RM-632_01 for RM-632 / FCCID: QTKRM-632 / IC: 661AD-RM632		
Testing has been carried out in accordance with:	ANSI C63.19-2007 American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids		
Documentation:	The documentation of the testing performed on the tested devices is archived for 15 years at TCC Nokia.		
Test results:	The tested device complies with the requirements in respect of all parameters subject to the test. The test results and statements relate only to the items tested. The test report shall not be reproduced except in full, without written approval of the laboratory.		
Date and signatures:			
For the contents:			

CONTENTS

1. SUMMARY OF HAC RF EMISSION TEST REPORT.....	3
1.1 TEST DETAILS	3
1.2 MAXIMUM RESULTS.....	3
1.2.1 Electric field measurements.....	3
1.2.2 Magnetic field measurements.....	3
1.2.3 Overall RF emissions category of the tested device.....	4
1.2.4 Maximum Drift	4
1.2.5 Measurement Uncertainty.....	4
2. DESCRIPTION OF THE DEVICE UNDER TEST (DUT).....	5
2.1 PICTURE OF DEVICE	5
3. TEST CONDITIONS.....	6
3.1 TEMPERATURE AND HUMIDITY	6
3.2 TEST SIGNAL, FREQUENCIES, AND OUTPUT POWER.....	6
4. DESCRIPTION OF THE TEST EQUIPMENT.....	7
4.1 MEASUREMENT SYSTEM AND COMPONENTS.....	7
4.1.1 Isotropic E-field probe ER3DV6	8
4.1.2 Isotropic H-field probe H3DV6	8
4.1.3 Device Holder.....	9
4.2 VALIDATION OF THE SYSTEM	9
5. DESCRIPTION OF THE TEST PROCEDURE.....	10
5.1 TEST ARCH AND DEVICE HOLDER.....	10
5.2 TEST POSITIONS	10
5.2.1 Scan area centered at the acoustic output.....	10
5.3 SCAN PROCEDURES.....	11
5.4 SCAN AREA CENTERED AT THE MAXIMUM MAGNETIC T-COIL COUPLING.....	11
5.5 PROBE MODULATION FACTOR	11
5.6 SLOT AVERAGED CALCULATION METHOD	12
5.7 SUB-GRID EXCLUSION	12
5.8 CATEGORY LIMITS.....	12
6. MEASUREMENT UNCERTAINTY	13
7. RESULTS.....	14
APPENDIX A: SYSTEM VALIDATION SCANS.....	15
APPENDIX B: MEASUREMENT SCANS.....	18
APPENDIX C: RELEVANT PAGES FROM PROBE CALIBRATION REPORT(S).....	30
APPENDIX D: RELEVANT PAGES FROM DIPOLE VALIDATION KIT REPORT(S).....	31

1. SUMMARY OF HAC RF EMISSION TEST REPORT

1.1 Test Details

Period of test	2010-04-26 to 2010-05-25
SN, HW, SW and DUT numbers of tested device	SN: 004401/10/933781/2, HW: 0200B, SW: 041.007, DUT: 14679 SN: 004401/01/987319/5, HW: 0202B, SW: 041.014, DUT: 14734
Batteries used in testing	BL-4D, DUT: 14680, 14681, 14682, 14732, 14733
State of sample	Prototype unit
Notes	AWF = -5 for GSM, 0 for WCDMA

1.2 Maximum Results

The maximum measured HAC RF emissions values and categories for electric and magnetic fields are given in section 1.2.1 and 1.2.2 respectively.

1.2.1 Electric field measurements

Band & Mode	Ch / Freq. [MHz]	Conducted power	Limit of E-field max. value in category M3 [V/m]	Maximum E-field value after exclusion [V/m]	Category
GSM850	251 / 848.8	32.0 dBm	149.6 – 266.1	208.7	M3 (-5dB)
WCDMA850	4132 / 826.4	22.0 dBm	199.5 – 354.8	41.5	M4 (0dB)
GSM1900	512 / 1850.2	29.0 dBm	47.3 – 84.1	55.4	M3 (-5dB)
WCDMA1900	9262 / 1852.4	22.0 dBm	63.1 – 112.2	13.3	M4 (0dB)

1.2.2 Magnetic field measurements

Band & Mode	Ch / Freq. [MHz]	Conducted power	Limit of H-field max. value in category M3 [A/m]	Maximum H-field value after exclusion [A/m]	Category
GSM850	251 / 848.8	32.0 dBm	0.45 – 0.80	0.376	M3 (-5dB)
WCDMA850	4233 / 846.6	22.0 dBm	0.60 – 1.07	0.086	M4 (0dB)
GSM1900	810 / 1909.8	29.0 dBm	0.14 – 0.25	0.126	M4 (-5dB)
WCDMA1900	9538 / 1907.6	22.0 dBm	0.19 – 0.34	0.035	M4 (0dB)

1.2.3 Overall RF emissions category of the tested device

Band & Mode	Combined category (E- and H-fields)	Pass / Fail
GSM850	M3	Pass
WCDMA850	M4	Pass
GSM1900	M3	Pass
WCDMA1900	M4	Pass
Final Category	M3	Pass

1.2.4 Maximum Drift

Maximum drift during measurements	0.31 dB
-----------------------------------	---------

1.2.5 Measurement Uncertainty

Extended Uncertainty (k=2) 95%, E-field	14.7 %
Extended Uncertainty (k=2) 95%, H-field	10.9 %

2. DESCRIPTION OF THE DEVICE UNDER TEST (DUT)

Modes of Operation	Bands	Modulation Mode	Duty Cycle	Transmitter Frequency Range (MHz)
GSM	850 1900	GMSK	1/8	824 – 849 1850 – 1910
WCDMA	850 (Band V) 1900 (Band II)	QPSK	1	826 – 847 1852 – 1908

Outside of USA the transmitter of the device is capable of operating also in 900MHz, 1800MHz and 2100MHz bands, which are not part of this filing.

2.1 Picture of Device



3. TEST CONDITIONS

3.1 Temperature and Humidity

Ambient temperature [°C]:	20.4 to 21.1
Ambient humidity [RH %]:	35 to 57

3.2 Test Signal, Frequencies, and Output Power

The transmitter of the device was put into operation by using a call tester. Communications between the device and the call tester were established by air link.

The measurements were performed on lowest, middle and highest channels.

For all tests the device output power was set to maximum power level; a fully charged battery was used for every test sequence.

The transmission mode of the device in WCDMA HAC RF emission tests was configured to 12.2kbps RMC with all TPC bits set as “1”.

Some of the HAC results given in this report have been copied from the earlier testing in RF_RM-632_01 for RM-632 / FCCID: QTKRM-632 / IC: 661AD-RM632. The difference between RM-632 and RM-634 is that RM-634 has had WCDMA900 components removed, but WCDMA850 components added.

4. DESCRIPTION OF THE TEST EQUIPMENT

4.1 Measurement system and components

The measurements were performed using an automated near-field scanning system, DASY 4, manufactured by Schmid & Partner Engineering AG (SPEAG) in Switzerland.
The following table lists calibration dates of SPEAG components:

Test Equipment	Serial Number	Calibration interval	Calibration expiry
DAE 4	1213	12 months	2010-11
E-field Probe ER3DV6	2309	12 months	2010-10
H-field Probe H3DV6	6143	12 months	2010-10
Dipole Validation Kit, CD835V3	1005	24 months	2010-11
Dipole Validation Kit, CD1880V3	1004	24 months	2010-11
DASY4 software	Version 4.7	-	-

Additional test equipment used in testing and validation:

Test Equipment	Model	Serial Number	Calibration interval	Calibration expiry
Signal Generator	SML03	101265	12 months	2010-09
Amplifier	ZHL-42 (SMA)	N072095-5	12 months	2010-09
Power Meter	NRVS	849305/028	12 months	2010-09
Power Sensor	NRV-Z32	839176/020	12 months	2010-09
Call Tester	CMU 200	101111	-	-

4.1.1 Isotropic E-field probe ER3DV6

Construction	One dipole parallel, two dipoles normal to probe axis Built-in shielding against static charges PEEK enclosure material
Frequency	In air 100 MHz to >6 GHz; Linearity: ± 0.2 dB (100 MHz to 3 GHz)
Directivity	± 0.2 dB in air (rotation around probe axis) ± 0.4 dB in air (rotation normal to probe axis)
Dynamic Range	2 V/m to > 1000 V/m; Linearity: ± 0.2 dB
Dimensions	Overall length: 330 mm Tip length: 16 mm Body diameter: 12 mm Tip diameter: 8 mm
Application	Distance from probe tip to nearest point of dipole: 1.25 mm General near-field measurements up to 6 GHz Field component measurements Fast automatic scanning in phantoms

4.1.2 Isotropic H-field probe H3DV6

Construction	Three concentric loop sensors with 3.8 mm loop diameters Resistively loaded detector diodes for linear response Built-in shielding against static charges PEEK enclosure material
Frequency	200 MHz to 3 GHz; Output linearized (absolute accuracy $\pm 6.0\%$, $k=2$)
Directivity	± 0.25 dB (spherical isotropy error)
Dynamic Range	10 mA/m to 2 A/m at 1 GHz
Dimensions	Overall length: 330 mm Tip length: 40 mm Body diameter: 12 mm Tip diameter: 6 mm
Application	Distance from probe tip to nearest point of dipole: 1.1 mm General magnetic near-field measurements up to 3 GHz Field component measurements, surface current measurements Measurements in air or liquids, low interaction

4.1.3 Device Holder

The Device Holder and Test Arch are manufactured by Speag (<http://www.dasy4.com/hac>). Test arch is used for all tests i.e. for both validation testing and device testing. The holder and test arch conforms to the requirements of ANSI C63.19.

The SPEAG device holder (see Section 5.1) was used to position the test device in all tests.

4.2 Validation of the System

The manufacturer calibrates the probes annually. Validation measurements are made regularly using the dipole validation kit. The power level used by manufacturer in dipole calibration is supplied to the dipole antenna. The antenna is scanned at 10mm distance between top surface of the dipole and calibration point of the probe.

System Validation, H-field and E-field

f [MHz]	Description	E-field [V/m]	H-field [A/m]
835	Reference result	164.1	0.441
	± 10% window	147.7 – 180.5	0.397 – 0.485
	2010-04-26	-	0.476
	2010-04-27	159.9	-
	2010-05-25	167.1	0.477
1880	Reference result	137.9	0.461
	± 10% window	124.1 – 151.7	0.415 – 0.507
	2010-04-26	-	0.447
	2010-04-27	140.7	-

Plots of the system validation scans are given in Appendix A.

5. DESCRIPTION OF THE TEST PROCEDURE

5.1 Test Arch and Device Holder

The test device was placed in the Device Holder (illustrated below) that is supplied by SPEAG. Using this positioner the tested device is positioned under Test Arch.



Device holder and Test Arch supplied by SPEAG

5.2 Test Positions

5.2.1 Scan area centered at the acoustic output

The device was positioned such that Device Reference plane was touching the bottom of the Test Arch. The scan is centered at the acoustic output by aligning the acoustic output with the intersection of the Test Arch's middle bar and dielectric wire.



Photo of the device positioned under Test Arch

5.3 Scan Procedures

Near field scans of 5cm x 5cm were used for determination of the field distribution. Measurement plane distance from WD reference plane is 15mm. Scans were performed for both E- and H-field using appropriate probe. DASY software divides detected values into 3 x 3 sub grids as described in the C63.19 standard.

5.4 Scan area centered at the maximum magnetic T-coil coupling

Scanning centered at the maximum magnetic T-coil coupling was not applicable for the tested device.

5.5 Probe Modulation Factor

All raw measurements in DASY4 system are presented as RMS values. The measurement software then applies Probe Modulation Factor (PMF) to convert readings to “slot averaged” peak values as required by C63.19 standard.

Therefore PMF was assessed as described in C63.19 standard along with Speag's Application Note (AN_Hearing_Aid_Compatibility.pdf, section 28.8, "Definition / Determination of the Probe Modulation Factor").

Observed Modulation Factor:

$$PMF_{(E)} = E\text{-field}_{(CW)} / E\text{-field}_{(Modulated)}$$

$$PMF_{(H)} = H\text{-field}_{(CW)} / H\text{-field}_{(Modulated)}$$

Observed Crest Factor:

$$CF_{(E)} = (PMF_{(E)})^2$$

$$CF_{(H)} = (PMF_{(H)})^2$$

Modulation factors, GSM

f [MHz]	P_{mod} [dBm]	E-field [V/m] Probe SN: 2309		H-field [A/m] Probe SN: 6143		PMF E-field	PMF H-field
		CW	GSM	CW	GSM		
835.0	20	99.6	34.7	0.459	0.169	2.87	2.72
1880.0	20	158.4	55.1	0.498	0.221	2.87	2.25

Modulation factors, WCDMA

f [MHz]	P_{mod} [dBm]	E-field [V/m] Probe SN: 2309		H-field [A/m] Probe SN: 6143		PMF E-field	PMF H-field
		CW	WCDMA	CW	WCDMA		
835.0	20	26.2	42.8	0.118	0.201	0.61	0.59
1880.0	20	36.3	60.1	0.112	0.217	0.60	0.52

5.6 Slot Averaged Calculation Method

The slot-averaged values for the every measured signal type were calculated using observed duty cycles.

5.7 Sub-grid Exclusion

The measurement grid defined in C63.19 consists of 9 evenly sized blocks, which are used to define permissible exclusion areas. For both E- and H-field measurements three contiguous blocks may be excluded from the measurements except center block may never be excluded. There must be 4 blocks left that are common for both E- and H-field measurements, so maximum of 5 different blocks can be excluded (e.g. 3 blocks excluded from E-field and 2 blocks from H-field).

5.8 Category Limits

From remaining maximum values after exclusion process, Hearing Aid M-category is defined according to the category limits of C63.19 – 2007.

		Limits for RF-parameters <960MHz	
Category	AWF [dB]	E-field [V/m]	H-field [A/m]
M1	0	631.0 to 1122.0	1.91 to 3.39
	-5	473.2 to 841.4	1.43 to 2.54
M2	0	354.8 to 631.0	1.07 to 1.91
	-5	266.1 to 473.2	0.80 to 1.43
M3	0	199.5 to 354.8	0.60 to 1.07
	-5	149.6 to 266.1	0.45 to 0.80
M4	0	<199.5	<0.60
	-5	<149.6	<0.45

		Limits for RF-parameters >960MHz	
Category	AWF [dB]	E-field [V/m]	H-field [A/m]
M1	0	199.5 to 354.8	0.60 to 1.07
	-5	149.6 to 266.1	0.45 to 0.80
M2	0	112.2 to 199.5	0.34 to 0.60
	-5	84.1 to 149.6	0.25 to 0.45
M3	0	63.1 to 112.2	0.19 to 0.34
	-5	47.3 to 84.1	0.14 to 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.14

6. MEASUREMENT UNCERTAINTY

Source of Uncertainty	Tolerance ±%	Prob. Dist.	Div.	ci E	ci H	Standard Uncertainty ±%, E	Standard Uncertainty ±%, H	Remark
MEASUREMENT SYSTEM								
Probe Calibration	5.1	N	1	1	1	5.1	5.1	
Axial Isotropy	4.7	R	√3	1	1	2.7	2.7	
Sensor Displacement	16.5	R	√3	1	0.145	9.5	1.4	
Boundary Effect	2.4	R	√3	1	1	1.4	1.4	
Linearity	4.7	R	√3	1	1	2.7	2.7	SAR
Scaling to Peak Envelope Power	2.0	R	√3	1	1	1.2	1.2	
System Detection Limit	1.0	R	√3	1	1	0.6	0.6	
Readout Electronics	0.3	N	1	1	1	0.3	0.3	SAR
Response Time	0.8	R	√3	1	1	0.5	0.5	
Integration Time	2.6	R	√3	1	1	1.5	1.5	SAR
RF Ambient Conditions	3.0	R	√3	1	1	1.7	1.7	SAR
RF Reflections	12.0	R	√3	1	1	6.9	6.9	
Probe Positioner	1.2	R	√3	1	0.67	0.7	0.5	
Probe Positioning	4.7	R	√3	1	0.67	2.7	1.8	
Extrapolation and Interpolation	1.0	R	√3	1	1	0.6	0.6	SAR
TEST SAMPLE RELATED								
Device Positioning Vertical	4.7	R	√3	1	0.67	2.7	1.8	
Device Positioning Lateral	1.0	R	√3	1	1	0.6	0.6	
Device Holder and Test Arch	2.4	R	√3	1	1	1.4	1.4	
Power Drift	5.0	R	√3	1	1	2.9	2.9	SAR
TEST ARCH AND SETUP RELATED								
Test Arch Thickness	2.4	R	√3	1	0.67	1.4	0.9	
Combined Standard Uncertainty						14.7	10.9	
Expanded Uncertainty on Power						29.4	21.8	
Expanded Uncertainty on Field						14.7	10.9	

7. RESULTS

The calculated maximum field values for the test device are tabulated below:

GSM850, RF emissions results

Mode	Test configuration	Ch 128 824.2 MHz	Ch 190 836.6 MHz	Ch 251 848.8 MHz
GSM850	Power	32.0 dBm	32.0 dBm	32.0 dBm
	E-field [V/m]	205.0	199.2	208.7
	H-field [A/m]	0.357	0.339	0.376
	Category	M3 (-5 dB)	M3 (-5 dB)	M3 (-5 dB)

WCDMA850, RF emissions results

Mode	Test configuration	Ch 4132 826.4 MHz	Ch 4175 835.0 MHz	Ch 4233 846.6 MHz
WCDMA850	Power	22.0 dBm	22.0 dBm	22.0 dBm
	E-field [V/m]	41.5	40.9	41.4
	H-field [A/m]	0.080	0.081	0.086
	Category	M4 (0 dB)	M4 (0 dB)	M4 (0 dB)

GSM1900, RF emissions results

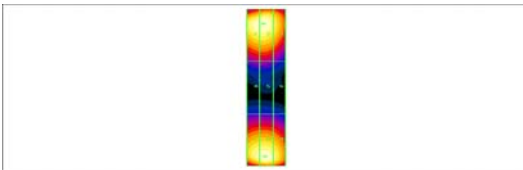
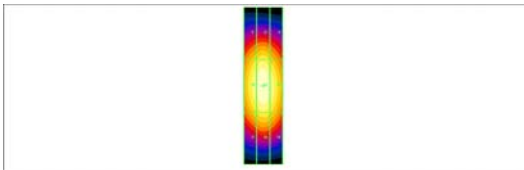
Mode	Test configuration	Ch 512 1850.2MHz	Ch 661 1880.0MHz	Ch 810 1909.8MHz
GSM1900	Power	29.0 dBm	29.0 dBm	29.0 dBm
	E-field [V/m]	55.4	47.2	49.8
	H-field [A/m]	0.102	0.118	0.126
	Category	M3 (-5 dB)	M4 (-5 dB)	M3 (-5 dB)

WCDMA1900, RF emissions results

Mode	Test configuration	Ch 9262 1852.4MHz	Ch 9400 1880.0MHz	Ch 9538 1907.6MHz
WCDMA1900	Power	22.0 dBm	22.0 dBm	22.0 dBm
	E-field [V/m]	13.3	12.4	12.4
	H-field [A/m]	0.030	0.034	0.035
	Category	M4 (0 dB)	M4 (0 dB)	M4 (0 dB)

Plots of the measurement scans are shown in **Appendix B**. Excluded cells are colored orange.

APPENDIX A: SYSTEM VALIDATION SCANS

SYSTEM VALIDATION DATA 850MHZ																			
Date/Time: 2010-04-27 11:46:22 Test Laboratory: TCC Nokia Type: CD835V3; Serial: 1005	Date/Time: 2010-04-26 14:55:19 Test Laboratory: TCC Nokia Type: CD835V3; Serial: 1005																		
Communication System: CW835 Frequency: 835 MHz; Duty Cycle: 1:1 Medium: Air; Medium Notes: - Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³ Phantom section: E Dipole Section	Communication System: CW835 Frequency: 835 MHz; Duty Cycle: 1:1 Medium: Air; Medium Notes: - Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³ Phantom section: H Dipole Section																		
DASY4 Configuration: - Probe: ER3DV6 - SN2309 - ConvF(1, 1, 1); Calibrated: 2009-10-27 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1213; Calibrated: 2009-11-16 - Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: - - Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184	DASY4 Configuration: - Probe: H3DV6 - SN6143 - ; Calibrated: 2009-10-23 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1213; Calibrated: 2009-11-16 - Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: - - Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184																		
E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 159.9 V/m Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, 354.7 mm Reference Value = 105.4 V/m; Power Drift = 0.068 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB) 159.9 136.2 112.5 88.9 65.2 41.5  <table><tr><td>Grid 1 158.9 M4</td><td>Grid 2 159.9 M4</td><td>Grid 3 147.6 M4</td></tr><tr><td>Grid 4 90.7 M4</td><td>Grid 5 91.4 M4</td><td>Grid 6 83.8 M4</td></tr><tr><td>Grid 7 156.0 M4</td><td>Grid 8 159.8 M4</td><td>Grid 9 151.9 M4</td></tr></table>	Grid 1 158.9 M4	Grid 2 159.9 M4	Grid 3 147.6 M4	Grid 4 90.7 M4	Grid 5 91.4 M4	Grid 6 83.8 M4	Grid 7 156.0 M4	Grid 8 159.8 M4	Grid 9 151.9 M4	H Scan - measurement distance from the probe sensor center to CD835 dipole= 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.476 A/m Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, 354.7 mm Reference Value = 0.509 A/m; Power Drift = -0.013 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB) 0.476 0.399 0.302 0.214 0.127 0.040  <table><tr><td>Grid 1 0.390 M4</td><td>Grid 2 0.409 M4</td><td>Grid 3 0.382 M4</td></tr><tr><td>Grid 4 0.451 M4</td><td>Grid 5 0.476 M4</td><td>Grid 6 0.449 M4</td></tr><tr><td>Grid 7 0.390 M4</td><td>Grid 8 0.415 M4</td><td>Grid 9 0.395 M4</td></tr></table>	Grid 1 0.390 M4	Grid 2 0.409 M4	Grid 3 0.382 M4	Grid 4 0.451 M4	Grid 5 0.476 M4	Grid 6 0.449 M4	Grid 7 0.390 M4	Grid 8 0.415 M4	Grid 9 0.395 M4
Grid 1 158.9 M4	Grid 2 159.9 M4	Grid 3 147.6 M4																	
Grid 4 90.7 M4	Grid 5 91.4 M4	Grid 6 83.8 M4																	
Grid 7 156.0 M4	Grid 8 159.8 M4	Grid 9 151.9 M4																	
Grid 1 0.390 M4	Grid 2 0.409 M4	Grid 3 0.382 M4																	
Grid 4 0.451 M4	Grid 5 0.476 M4	Grid 6 0.449 M4																	
Grid 7 0.390 M4	Grid 8 0.415 M4	Grid 9 0.395 M4																	

SYSTEM VALIDATION DATA 850MHz

Date/Time: 2010-05-25 12:58:16
Test Laboratory: TCC Nokia
Type: CD835V3; Serial: 1005

Date/Time: 2010-05-25 11:24:10
Test Laboratory: TCC Nokia
Type: CD835V3; Serial: 1005

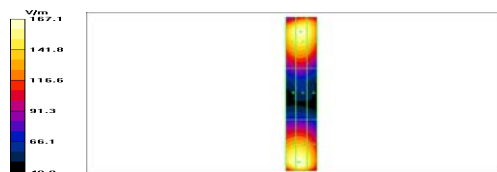
Communication System: CW
Frequency: 835 MHz; Duty Cycle: 1:1
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³
Phantom section: E Dipole Section

Communication System: CW
Frequency: 835 MHz; Duty Cycle: 1:1
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³
Phantom section: H Dipole Section

DASY4 Configuration:
- Probe: ER3DV6 - SN2309
- ConvF(1, 1, 1); Calibrated: 2009-10-27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1213; Calibrated: 2009-11-16
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

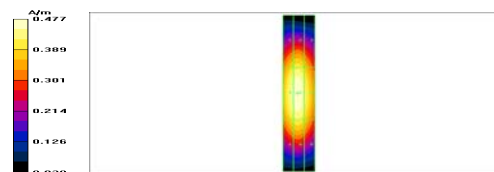
DASY4 Configuration:
- Probe: H3DV6 - SN6143
- ; Calibrated: 2009-10-23
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1213; Calibrated: 2009-11-16
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 167.1 V/m
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, 354.7 mm
Reference Value = 106.9 V/m; Power Drift = 0.044 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

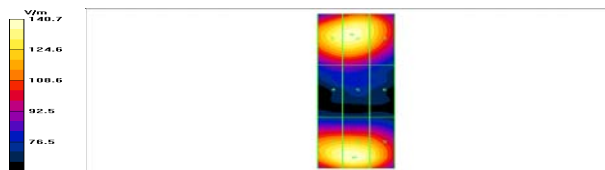
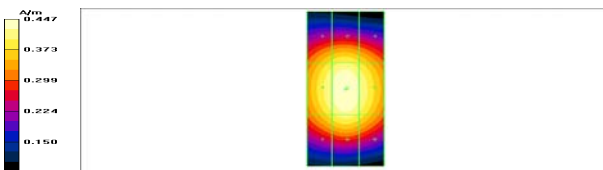


Grid 1 158.5 M4	Grid 2 161.7 M4	Grid 3 157.4 M4
Grid 4 91.0 M4	Grid 5 93.2 M4	Grid 6 88.6 M4
Grid 7 165.1 M4	Grid 8 167.1 M4	Grid 9 155.1 M4

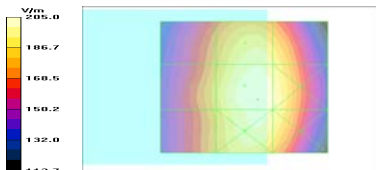
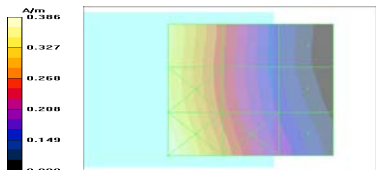
H Scan - measurement distance from the probe sensor center to CD835 dipole= 10mm/Hearing Aid Compatibility Test (41x361x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.477 A/m
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, 354.7 mm
Reference Value = 0.505 A/m; Power Drift = 0.062 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)



Grid 1 0.397 M4	Grid 2 0.412 M4	Grid 3 0.376 M4
Grid 4 0.461 M4	Grid 5 0.477 M4	Grid 6 0.437 M4
Grid 7 0.404 M4	Grid 8 0.419 M4	Grid 9 0.384 M4

SYSTEM VALIDATION DATA 1900MHz																			
Date/Time: 2010-04-27 11:24:08 Test Laboratory: TCC Nokia Type: CD1880V3; Serial: 1004	Date/Time: 2010-04-26 15:10:01 Test Laboratory: TCC Nokia Type: CD1880V3; Serial: 1004																		
Communication System: CW1880 Frequency: 1880 MHz; Duty Cycle: 1:1 Medium: Air; Medium Notes: - Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³ Phantom section: E Dipole Section	Communication System: CW1880 Frequency: 1880 MHz; Duty Cycle: 1:1 Medium: Air; Medium Notes: - Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³ Phantom section: H Dipole Section																		
DASY4 Configuration: - Probe: ER3DV6 - SN2309 - ConvF(1, 1, 1); Calibrated: 2009-10-27 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1213; Calibrated: 2009-11-16 - Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: - - Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184	DASY4 Configuration: - Probe: H3DV6 - SN6143 - ; Calibrated: 2009-10-23 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1213; Calibrated: 2009-11-16 - Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: - - Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184																		
E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 140.7 V/m Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, 354.7 mm Reference Value = 157.0 V/m; Power Drift = 0.057 dB Hearing Aid Near-Field Category: M2 (AWF 0 dB) <table><tr><td>Grid 1 136.5 M2</td><td>Grid 2 138.7 M2</td><td>Grid 3 129.9 M2</td></tr><tr><td>Grid 4 91.8 M3</td><td>Grid 5 91.9 M3</td><td>Grid 6 85.2 M3</td></tr><tr><td>Grid 7 137.7 M2</td><td>Grid 8 140.7 M2</td><td>Grid 9 132.3 M2</td></tr></table>	Grid 1 136.5 M2	Grid 2 138.7 M2	Grid 3 129.9 M2	Grid 4 91.8 M3	Grid 5 91.9 M3	Grid 6 85.2 M3	Grid 7 137.7 M2	Grid 8 140.7 M2	Grid 9 132.3 M2	H Scan - measurement distance from the probe sensor center to CD1880 dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.447 A/m Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, 354.7 mm Reference Value = 0.474 A/m; Power Drift = 0.027 dB Hearing Aid Near-Field Category: M2 (AWF 0 dB) <table><tr><td>Grid 1 0.384 M2</td><td>Grid 2 0.401 M2</td><td>Grid 3 0.379 M2</td></tr><tr><td>Grid 4 0.424 M2</td><td>Grid 5 0.447 M2</td><td>Grid 6 0.424 M2</td></tr><tr><td>Grid 7 0.389 M2</td><td>Grid 8 0.413 M2</td><td>Grid 9 0.391 M2</td></tr></table>	Grid 1 0.384 M2	Grid 2 0.401 M2	Grid 3 0.379 M2	Grid 4 0.424 M2	Grid 5 0.447 M2	Grid 6 0.424 M2	Grid 7 0.389 M2	Grid 8 0.413 M2	Grid 9 0.391 M2
Grid 1 136.5 M2	Grid 2 138.7 M2	Grid 3 129.9 M2																	
Grid 4 91.8 M3	Grid 5 91.9 M3	Grid 6 85.2 M3																	
Grid 7 137.7 M2	Grid 8 140.7 M2	Grid 9 132.3 M2																	
Grid 1 0.384 M2	Grid 2 0.401 M2	Grid 3 0.379 M2																	
Grid 4 0.424 M2	Grid 5 0.447 M2	Grid 6 0.424 M2																	
Grid 7 0.389 M2	Grid 8 0.413 M2	Grid 9 0.391 M2																	

APPENDIX B: MEASUREMENT SCANS

MEASUREMENT DATA GSM850, CHANNEL LOW (824.2 MHz)																			
Date/Time: 2010-04-28 12:10:58 Test Laboratory: TCC Nokia Type: RM-632; Serial: 004401/10/933781/2	Date/Time: 2010-04-28 14:09:31 Test Laboratory: TCC Nokia Type: RM-632; Serial: 004401/10/933781/2																		
Communication System: GSM850 (ER3DV6) Frequency: 824.2 MHz; Duty Cycle: 1:8.26 Medium: Air; Medium Notes: - Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³ Phantom section: E Device Section	Communication System: GSM850 (H3DV6) Frequency: 824.2 MHz; Duty Cycle: 1:7.39 Medium: Air; Medium Notes: - Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³ Phantom section: H Device Section																		
DASY4 Configuration: - Probe: ER3DV6 - SN2309 - ConvF(1, 1, 1); Calibrated: 2009-10-27 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1213; Calibrated: 2009-11-16 - Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: - - Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184	DASY4 Configuration: - Probe: H3DV6 - SN6143 - ; Calibrated: 2009-10-23 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1213; Calibrated: 2009-11-16 - Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: - - Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184																		
E Scan - Low - measurement distance, sensor center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 205.0 V/m Probe Modulation Factor = 2.87 Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 92.0 V/m; Power Drift = 0.014 dB Hearing Aid Near-Field Category: M3 (AWF -5 dB)  <table><tr><td>Grid 1 177.8 M3</td><td>Grid 2 198.7 M3</td><td>Grid 3 194.2 M3</td></tr><tr><td>Grid 4 184.2 M3</td><td>Grid 5 205.0 M3</td><td>Grid 6 200.4 M3</td></tr><tr><td>Grid 7 182.1 M3</td><td>Grid 8 202.6 M3</td><td>Grid 9 198.3 M3</td></tr></table>	Grid 1 177.8 M3	Grid 2 198.7 M3	Grid 3 194.2 M3	Grid 4 184.2 M3	Grid 5 205.0 M3	Grid 6 200.4 M3	Grid 7 182.1 M3	Grid 8 202.6 M3	Grid 9 198.3 M3	H Scan - Low - measurement distance, sensor center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.357 A/m Probe Modulation Factor = 2.72 Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 0.075 A/m; Power Drift = -0.002 dB Hearing Aid Near-Field Category: M4 (AWF -5 dB)  <table><tr><td>Grid 1 0.357 M4</td><td>Grid 2 0.256 M4</td><td>Grid 3 0.154 M4</td></tr><tr><td>Grid 4 0.358 M4</td><td>Grid 5 0.260 M4</td><td>Grid 6 0.167 M4</td></tr><tr><td>Grid 7 0.386 M4</td><td>Grid 8 0.285 M4</td><td>Grid 9 0.189 M4</td></tr></table>	Grid 1 0.357 M4	Grid 2 0.256 M4	Grid 3 0.154 M4	Grid 4 0.358 M4	Grid 5 0.260 M4	Grid 6 0.167 M4	Grid 7 0.386 M4	Grid 8 0.285 M4	Grid 9 0.189 M4
Grid 1 177.8 M3	Grid 2 198.7 M3	Grid 3 194.2 M3																	
Grid 4 184.2 M3	Grid 5 205.0 M3	Grid 6 200.4 M3																	
Grid 7 182.1 M3	Grid 8 202.6 M3	Grid 9 198.3 M3																	
Grid 1 0.357 M4	Grid 2 0.256 M4	Grid 3 0.154 M4																	
Grid 4 0.358 M4	Grid 5 0.260 M4	Grid 6 0.167 M4																	
Grid 7 0.386 M4	Grid 8 0.285 M4	Grid 9 0.189 M4																	

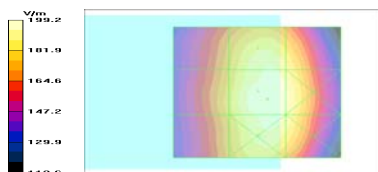
MEASUREMENT DATA GSM850, CHANNEL MIDDLE (836.6 MHz)

Date/Time: 2010-04-28 11:51:39
Test Laboratory: TCC Nokia
Type: RM-632; Serial: 004401/10/933781/2

Communication System: GSM850 (ER3DV6)
Frequency: 836.6 MHz; Duty Cycle: 1:8.26
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³
Phantom section: E Device Section

DASY4 Configuration:
- Probe: ER3DV6 - SN2309
- ConvF(1, 1, 1); Calibrated: 2009-10-27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1213; Calibrated: 2009-11-16
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

E Scan -Middle - measurement distance, sensor center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 199.2 V/m
Probe Modulation Factor = 2.87
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 89.2 V/m; Power Drift = 0.007 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)



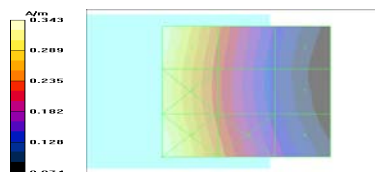
Grid 1 175.4 M3	Grid 2 194.5 M3	Grid 3 190.0 M3
Grid 4 180.3 M3	Grid 5 199.2 M3	Grid 6 195.3 M3
Grid 7 177.6 M3	Grid 8 197.2 M3	Grid 9 192.9 M3

Date/Time: 2010-04-28 13:58:27
Test Laboratory: TCC Nokia
Type: RM-632; Serial: 004401/10/933781/2

Communication System: GSM850 (H3DV6)
Frequency: 836.6 MHz; Duty Cycle: 1:7.39
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³
Phantom section: H Device Section

DASY4 Configuration:
- Probe: H3DV6 - SN6143
- ; Calibrated: 2009-10-23
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1213; Calibrated: 2009-11-16
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

H Scan - Middle - Measurement distance, sensor center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.339 A/m
Probe Modulation Factor = 2.72
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 0.065 A/m; Power Drift = 0.018 dB
Hearing Aid Near-Field Category: M4 (AWF -5 dB)



Grid 1 0.339 M4	Grid 2 0.240 M4	Grid 3 0.145 M4
Grid 4 0.327 M4	Grid 5 0.229 M4	Grid 6 0.137 M4
Grid 7 0.343 M4	Grid 8 0.249 M4	Grid 9 0.158 M4

MEASUREMENT DATA GSM850, CHANNEL HIGH (848.8 MHz)

Date/Time: 2010-04-28 11:59:33
Test Laboratory: TCC Nokia
Type: RM-632; Serial: 004401/10/933781/2

Date/Time: 2010-04-28 14:04:05
Test Laboratory: TCC Nokia
Type: RM-632; Serial: 004401/10/933781/2

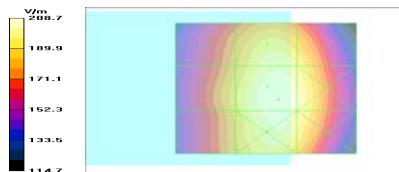
Communication System: GSM850 (ER3DV6)
Frequency: 848.8 MHz; Duty Cycle: 1:8.26
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³
Phantom section: E Device Section

Communication System: GSM850 (H3DV6)
Frequency: 848.8 MHz; Duty Cycle: 1:7.39
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³
Phantom section: H Device Section

DASY4 Configuration:
- Probe: ER3DV6 - SN2309
- ConvF(1, 1, 1); Calibrated: 2009-10-27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1213; Calibrated: 2009-11-16
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

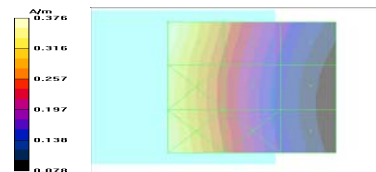
DASY4 Configuration:
- Probe: H3DV6 - SN6143
- ; Calibrated: 2009-10-23
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1213; Calibrated: 2009-11-16
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

E Scan - High - measurement distance, sensor center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 208.7 V/m
Probe Modulation Factor = 2.87
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 93.2 V/m; Power Drift = -0.026 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)



Grid 1 181.7 M3	Grid 2 201.5 M3	Grid 3 196.7 M3
Grid 4 188.7 M3	Grid 5 208.7 M3	Grid 6 203.9 M3
Grid 7 185.8 M3	Grid 8 206.7 M3	Grid 9 202.1 M3

H Scan - High - measurement distance, sensor center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.376 A/m
Probe Modulation Factor = 2.72
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 0.072 A/m; Power Drift = -0.053 dB
Hearing Aid Near-Field Category: M4 (AWF -5 dB)



Grid 1 0.376 M4	Grid 2 0.273 M4	Grid 3 0.171 M4
Grid 4 0.354 M4	Grid 5 0.250 M4	Grid 6 0.150 M4
Grid 7 0.361 M4	Grid 8 0.256 M4	Grid 9 0.155 M4

MEASUREMENT DATA WCDMA850, CHANNEL LOW (826.4 MHz)

Date/Time: 2010-05-25 13:18:51
Test Laboratory: TCC Nokia
Type: RM-634; Serial: 004401/01/987319/5

Date/Time: 2010-05-25 11:58:54
Test Laboratory: TCC Nokia
Type: RM-634; Serial: 004401/01/987319/5

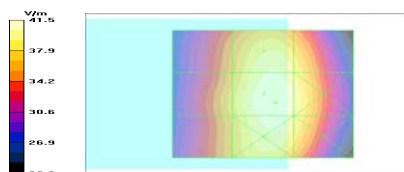
Communication System: WCDMA850 (ER3DV6)
Frequency: 826.4 MHz; Duty Cycle: 1:1
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³
Phantom section: E Device Section

Communication System: WCDMA850 (H3DV6)
Frequency: 826.4 MHz; Duty Cycle: 1:1
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³
Phantom section: H Device Section

DASY4 Configuration:
- Probe: ER3DV6 - SN2309
- ConvF(1, 1, 1); Calibrated: 2009-10-27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1213; Calibrated: 2009-11-16
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

DASY4 Configuration:
- Probe: H3DV6 - SN6143
- ; Calibrated: 2009-10-23
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1213; Calibrated: 2009-11-16
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

E Scan - Low - measurement distance, sensor center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 41.5 V/m
Probe Modulation Factor = 0.610
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 87.9 V/m; Power Drift = -0.038 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

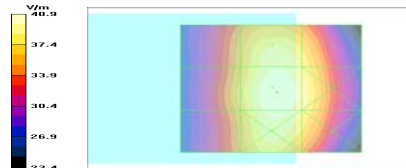


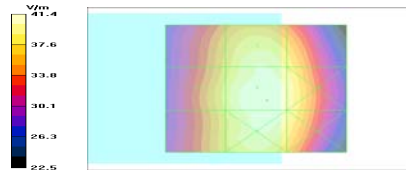
Grid 1 36.2 M4	Grid 2 40.5 M4	Grid 3 39.3 M4
Grid 4 37.4 M4	Grid 5 41.5 M4	Grid 6 40.3 M4
Grid 7 37.0 M4	Grid 8 41.1 M4	Grid 9 39.8 M4

H Scan - Low - measurement distance, sensor center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.080 A/m
Probe Modulation Factor = 0.590
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 0.075 A/m; Power Drift = 0.016 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

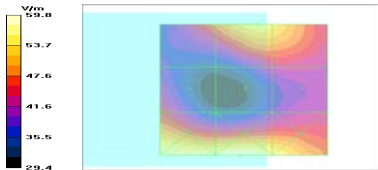


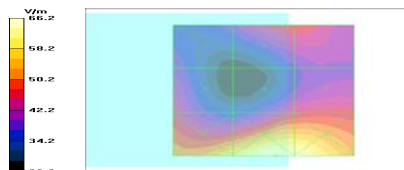
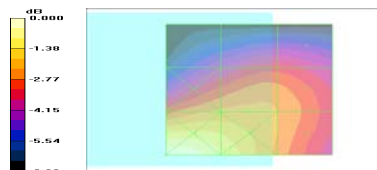
Grid 1 0.080 M4	Grid 2 0.058 M4	Grid 3 0.034 M4
Grid 4 0.078 M4	Grid 5 0.057 M4	Grid 6 0.037 M4
Grid 7 0.086 M4	Grid 8 0.064 M4	Grid 9 0.042 M4

MEASUREMENT DATA WCDMA850, CHANNEL MIDDLE (835 MHz)																			
Date/Time: 2010-05-25 13:09:02 Test Laboratory: TCC Nokia Type: RM-634; Serial: 004401/01/987319/5	Date/Time: 2010-05-25 11:48:44 Test Laboratory: TCC Nokia Type: RM-634; Serial: 004401/01/987319/5																		
Communication System: WCDMA850 (ER3DV6) Frequency: 835 MHz; Duty Cycle: 1:1 Medium: Air; Medium Notes: - Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³ Phantom section: E Device Section	Communication System: WCDMA850 (H3DV6) Frequency: 835 MHz; Duty Cycle: 1:1 Medium: Air; Medium Notes: - Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³ Phantom section: H Device Section																		
DASY4 Configuration: - Probe: ER3DV6 - SN2309 - ConvF(1, 1, 1); Calibrated: 2009-10-27 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1213; Calibrated: 2009-11-16 - Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: - - Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184	DASY4 Configuration: - Probe: H3DV6 - SN6143 - ; Calibrated: 2009-10-23 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1213; Calibrated: 2009-11-16 - Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: - - Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184																		
E Scan -Middle - measurement distance, sensor center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 40.9 V/m Probe Modulation Factor = 0.610 Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 86.5 V/m; Power Drift = -0.075 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)  <table><tr><td>Grid 1 36.0 M4</td><td>Grid 2 39.7 M4</td><td>Grid 3 38.6 M4</td></tr><tr><td>Grid 4 36.8 M4</td><td>Grid 5 40.9 M4</td><td>Grid 6 39.4 M4</td></tr><tr><td>Grid 7 36.2 M4</td><td>Grid 8 40.3 M4</td><td>Grid 9 38.8 M4</td></tr></table>	Grid 1 36.0 M4	Grid 2 39.7 M4	Grid 3 38.6 M4	Grid 4 36.8 M4	Grid 5 40.9 M4	Grid 6 39.4 M4	Grid 7 36.2 M4	Grid 8 40.3 M4	Grid 9 38.8 M4	H Scan - Middle - Measurement distance, sensor center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.081 A/m Probe Modulation Factor = 0.590 Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 0.073 A/m; Power Drift = -0.045 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)  <table><tr><td>Grid 1 0.081 M4</td><td>Grid 2 0.058 M4</td><td>Grid 3 0.035 M4</td></tr><tr><td>Grid 4 0.075 M4</td><td>Grid 5 0.055 M4</td><td>Grid 6 0.035 M4</td></tr><tr><td>Grid 7 0.082 M4</td><td>Grid 8 0.062 M4</td><td>Grid 9 0.041 M4</td></tr></table>	Grid 1 0.081 M4	Grid 2 0.058 M4	Grid 3 0.035 M4	Grid 4 0.075 M4	Grid 5 0.055 M4	Grid 6 0.035 M4	Grid 7 0.082 M4	Grid 8 0.062 M4	Grid 9 0.041 M4
Grid 1 36.0 M4	Grid 2 39.7 M4	Grid 3 38.6 M4																	
Grid 4 36.8 M4	Grid 5 40.9 M4	Grid 6 39.4 M4																	
Grid 7 36.2 M4	Grid 8 40.3 M4	Grid 9 38.8 M4																	
Grid 1 0.081 M4	Grid 2 0.058 M4	Grid 3 0.035 M4																	
Grid 4 0.075 M4	Grid 5 0.055 M4	Grid 6 0.035 M4																	
Grid 7 0.082 M4	Grid 8 0.062 M4	Grid 9 0.041 M4																	

MEASUREMENT DATA WCDMA850, CHANNEL HIGH (846.6 MHz)																			
Date/Time: 2010-05-25 13:13:54 Test Laboratory: TCC Nokia Type: RM-634; Serial: 004401/01/987319/5	Date/Time: 2010-05-25 11:53:36 Test Laboratory: TCC Nokia Type: RM-634; Serial: 004401/01/987319/5																		
Communication System: WCDMA850 (ER3DV6) Frequency: 846.6 MHz; Duty Cycle: 1:1 Medium: Air; Medium Notes: - Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m ³ Phantom section: E Device Section	Communication System: WCDMA850 (H3DV6) Frequency: 846.6 MHz; Duty Cycle: 1:1 Medium: Air; Medium Notes: - Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m ³ Phantom section: H Device Section																		
DASY4 Configuration: - Probe: ER3DV6 - SN2309 - ConvF(1, 1, 1); Calibrated: 2009-10-27 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1213; Calibrated: 2009-11-16 - Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: - - Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184	DASY4 Configuration: - Probe: H3DV6 - SN6143 - ; Calibrated: 2009-10-23 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1213; Calibrated: 2009-11-16 - Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: - - Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184																		
E Scan - High - measurement distance, sensor center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 41.4 V/m Probe Modulation Factor = 0.610 Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 88.9 V/m; Power Drift = -0.110 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)	H Scan - High - measurement distance, sensor center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.086 A/m Probe Modulation Factor = 0.590 Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 0.073 A/m; Power Drift = -0.055 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)																		
 <table><tr><td>Grid 1 36.9 M4</td><td>Grid 2 40.3 M4</td><td>Grid 3 38.7 M4</td></tr><tr><td>Grid 4 38.2 M4</td><td>Grid 5 41.4 M4</td><td>Grid 6 40.0 M4</td></tr><tr><td>Grid 7 37.8 M4</td><td>Grid 8 41.3 M4</td><td>Grid 9 39.7 M4</td></tr></table>	Grid 1 36.9 M4	Grid 2 40.3 M4	Grid 3 38.7 M4	Grid 4 38.2 M4	Grid 5 41.4 M4	Grid 6 40.0 M4	Grid 7 37.8 M4	Grid 8 41.3 M4	Grid 9 39.7 M4	 <table><tr><td>Grid 1 0.086 M4</td><td>Grid 2 0.062 M4</td><td>Grid 3 0.038 M4</td></tr><tr><td>Grid 4 0.079 M4</td><td>Grid 5 0.056 M4</td><td>Grid 6 0.033 M4</td></tr><tr><td>Grid 7 0.082 M4</td><td>Grid 8 0.058 M4</td><td>Grid 9 0.035 M4</td></tr></table>	Grid 1 0.086 M4	Grid 2 0.062 M4	Grid 3 0.038 M4	Grid 4 0.079 M4	Grid 5 0.056 M4	Grid 6 0.033 M4	Grid 7 0.082 M4	Grid 8 0.058 M4	Grid 9 0.035 M4
Grid 1 36.9 M4	Grid 2 40.3 M4	Grid 3 38.7 M4																	
Grid 4 38.2 M4	Grid 5 41.4 M4	Grid 6 40.0 M4																	
Grid 7 37.8 M4	Grid 8 41.3 M4	Grid 9 39.7 M4																	
Grid 1 0.086 M4	Grid 2 0.062 M4	Grid 3 0.038 M4																	
Grid 4 0.079 M4	Grid 5 0.056 M4	Grid 6 0.033 M4																	
Grid 7 0.082 M4	Grid 8 0.058 M4	Grid 9 0.035 M4																	

MEASUREMENT DATA GSM1900, CHANNEL LOW (1850.2 MHz)

Date/Time: 2010-04-28 11:43:10 Test Laboratory: TCC Nokia Type: RM-632; Serial: 004401/10/933781/2	Date/Time: 2010-04-28 13:51:58 Test Laboratory: TCC Nokia Type: RM-632; Serial: 004401/10/933781/2																		
Communication System: GSM1900 (ER3DV6) Frequency: 1850.2 MHz; Duty Cycle: 1:8.26 Medium: Air; Medium Notes: - Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³ Phantom section: E Device Section	Communication System: GSM1900 (H3DV6) Frequency: 1850.2 MHz; Duty Cycle: 1:5.07 Medium: Air; Medium Notes: - Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³ Phantom section: H Device Section																		
DASY4 Configuration: - Probe: ER3DV6 - SN2309 - ConvF(1, 1, 1); Calibrated: 2009-10-27 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1213; Calibrated: 2009-11-16 - Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: - - Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184	DASY4 Configuration: - Probe: H3DV6 - SN6143 - ; Calibrated: 2009-10-23 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1213; Calibrated: 2009-11-16 - Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: - - Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184																		
E Scan - Low - measurement distance, sensor center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 55.4 V/m Probe Modulation Factor = 2.87 Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 10.9 V/m; Power Drift = -0.011 dB Hearing Aid Near-Field Category: M3 (AWF -5 dB)  <table><tr><td>Grid 1 48.8 M3</td><td>Grid 2 55.4 M3</td><td>Grid 3 54.6 M3</td></tr><tr><td>Grid 4 45.1 M4</td><td>Grid 5 42.0 M4</td><td>Grid 6 42.7 M4</td></tr><tr><td>Grid 7 58.3 M3</td><td>Grid 8 59.8 M3</td><td>Grid 9 56.7 M3</td></tr></table>	Grid 1 48.8 M3	Grid 2 55.4 M3	Grid 3 54.6 M3	Grid 4 45.1 M4	Grid 5 42.0 M4	Grid 6 42.7 M4	Grid 7 58.3 M3	Grid 8 59.8 M3	Grid 9 56.7 M3	H Scan - Low - measurement distance, sensor center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.102 A/m Probe Modulation Factor = 2.25 Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 0.046 A/m; Power Drift = 0.025 dB Hearing Aid Near-Field Category: M4 (AWF -5 dB)  <table><tr><td>Grid 1 0.102 M4</td><td>Grid 2 0.087 M4</td><td>Grid 3 0.087 M4</td></tr><tr><td>Grid 4 0.102 M4</td><td>Grid 5 0.102 M4</td><td>Grid 6 0.102 M4</td></tr><tr><td>Grid 7 0.134 M4</td><td>Grid 8 0.117 M4</td><td>Grid 9 0.102 M4</td></tr></table>	Grid 1 0.102 M4	Grid 2 0.087 M4	Grid 3 0.087 M4	Grid 4 0.102 M4	Grid 5 0.102 M4	Grid 6 0.102 M4	Grid 7 0.134 M4	Grid 8 0.117 M4	Grid 9 0.102 M4
Grid 1 48.8 M3	Grid 2 55.4 M3	Grid 3 54.6 M3																	
Grid 4 45.1 M4	Grid 5 42.0 M4	Grid 6 42.7 M4																	
Grid 7 58.3 M3	Grid 8 59.8 M3	Grid 9 56.7 M3																	
Grid 1 0.102 M4	Grid 2 0.087 M4	Grid 3 0.087 M4																	
Grid 4 0.102 M4	Grid 5 0.102 M4	Grid 6 0.102 M4																	
Grid 7 0.134 M4	Grid 8 0.117 M4	Grid 9 0.102 M4																	

MEASUREMENT DATA GSM1900, CHANNEL MIDDLE (1880 MHz)																																																							
Date/Time: 2010-04-28 11:31:09 Test Laboratory: TCC Nokia Type: RM-632; Serial: 004401/10/933781/2	Date/Time: 2010-04-28 13:37:56 Test Laboratory: TCC Nokia Type: RM-632; Serial: 004401/10/933781/2																																																						
Communication System: GSM1900 (ER3DV6) Frequency: 1880 MHz; Duty Cycle: 1:8.26 Medium: Air; Medium Notes: - Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m ³ Phantom section: E Device Section	Communication System: GSM1900 (H3DV6) Frequency: 1880 MHz; Duty Cycle: 1:5.07 Medium: Air; Medium Notes: - Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m ³ Phantom section: H Device Section																																																						
DASY4 Configuration: - Probe: ER3DV6 - SN2309 - ConvF(1, 1, 1); Calibrated: 2009-10-27 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1213; Calibrated: 2009-11-16 - Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: - - Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184	DASY4 Configuration: - Probe: H3DV6 - SN6143 - ; Calibrated: 2009-10-23 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1213; Calibrated: 2009-11-16 - Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: - - Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184																																																						
E Scan -Middle - measurement distance, sensor center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 47.2 V/m Probe Modulation Factor = 2.87 Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 10.8 V/m; Power Drift = -0.046 dB Hearing Aid Near-Field Category: M4 (AWF -5 dB)	H Scan - Middle - Measurement distance, sensor center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.118 A/m Probe Modulation Factor = 2.25 Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 0.053 A/m; Power Drift = 0.030 dB Hearing Aid Near-Field Category: M4 (AWF -5 dB)																																																						
 <table><tr><td>Grid 1</td><td>Grid 2</td><td>Grid 3</td></tr><tr><td>39.5</td><td>47.2</td><td>47.0</td></tr><tr><td>M4</td><td>M4</td><td>M4</td></tr><tr><td>Grid 4</td><td>Grid 5</td><td>Grid 6</td></tr><tr><td>45.0</td><td>44.9</td><td>46.5</td></tr><tr><td>M4</td><td>M4</td><td>M4</td></tr><tr><td>Grid 7</td><td>Grid 8</td><td>Grid 9</td></tr><tr><td>59.6</td><td>66.2</td><td>64.8</td></tr><tr><td>M3</td><td>M3</td><td>M3</td></tr></table>	Grid 1	Grid 2	Grid 3	39.5	47.2	47.0	M4	M4	M4	Grid 4	Grid 5	Grid 6	45.0	44.9	46.5	M4	M4	M4	Grid 7	Grid 8	Grid 9	59.6	66.2	64.8	M3	M3	M3	 <table><tr><td>Grid 1</td><td>Grid 2</td><td>Grid 3</td></tr><tr><td>0.093</td><td>0.101</td><td>0.101</td></tr><tr><td>M4</td><td>M4</td><td>M4</td></tr><tr><td>Grid 4</td><td>Grid 5</td><td>Grid 6</td></tr><tr><td>0.117</td><td>0.118</td><td>0.115</td></tr><tr><td>M4</td><td>M4</td><td>M4</td></tr><tr><td>Grid 7</td><td>Grid 8</td><td>Grid 9</td></tr><tr><td>0.150</td><td>0.136</td><td>0.115</td></tr><tr><td>M3</td><td>M4</td><td>M4</td></tr></table>	Grid 1	Grid 2	Grid 3	0.093	0.101	0.101	M4	M4	M4	Grid 4	Grid 5	Grid 6	0.117	0.118	0.115	M4	M4	M4	Grid 7	Grid 8	Grid 9	0.150	0.136	0.115	M3	M4	M4
Grid 1	Grid 2	Grid 3																																																					
39.5	47.2	47.0																																																					
M4	M4	M4																																																					
Grid 4	Grid 5	Grid 6																																																					
45.0	44.9	46.5																																																					
M4	M4	M4																																																					
Grid 7	Grid 8	Grid 9																																																					
59.6	66.2	64.8																																																					
M3	M3	M3																																																					
Grid 1	Grid 2	Grid 3																																																					
0.093	0.101	0.101																																																					
M4	M4	M4																																																					
Grid 4	Grid 5	Grid 6																																																					
0.117	0.118	0.115																																																					
M4	M4	M4																																																					
Grid 7	Grid 8	Grid 9																																																					
0.150	0.136	0.115																																																					
M3	M4	M4																																																					

MEASUREMENT DATA GSM1900, CHANNEL HIGH (1909.8 MHz)

Date/Time: 2010-04-28 11:38:09
Test Laboratory: TCC Nokia
Type: RM-632; Serial: 004401/10/933781/2

Date/Time: 2010-04-28 13:46:51
Test Laboratory: TCC Nokia
Type: RM-632; Serial: 004401/10/933781/2

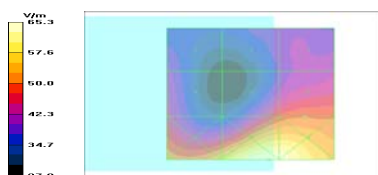
Communication System: GSM1900 (ER3DV6)
Frequency: 1909.8 MHz; Duty Cycle: 1:8.26
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³
Phantom section: E Device Section

Communication System: GSM1900 (H3DV6)
Frequency: 1909.8 MHz; Duty Cycle: 1:5.07
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³
Phantom section: H Device Section

DASY4 Configuration:
- Probe: ER3DV6 - SN2309
- ConvF(1, 1, 1); Calibrated: 2009-10-27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1213; Calibrated: 2009-11-16
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

DASY4 Configuration:
- Probe: H3DV6 - SN6143
- ; Calibrated: 2009-10-23
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1213; Calibrated: 2009-11-16
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

E Scan - High - measurement distance, sensor center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 49.8 V/m
Probe Modulation Factor = 2.87
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 11.8 V/m; Power Drift = -0.062 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)



Grid 1 40.7 M4	Grid 2 39.6 M4	Grid 3 41.9 M4
Grid 4 44.3 M4	Grid 5 47.9 M3	Grid 6 49.8 M3
Grid 7 56.0 M3	Grid 8 65.3 M3	Grid 9 64.8 M3

H Scan - High - measurement distance, sensor center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.126 A/m
Probe Modulation Factor = 2.25
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 0.055 A/m; Power Drift = 0.046 dB
Hearing Aid Near-Field Category: M4 (AWF -5 dB)



Grid 1 0.091 M4	Grid 2 0.101 M4	Grid 3 0.101 M4
Grid 4 0.125 M4	Grid 5 0.126 M4	Grid 6 0.124 M4
Grid 7 0.167 M3	Grid 8 0.153 M3	Grid 9 0.130 M4

MEASUREMENT DATA WCDMA1900, CHANNEL LOW (1852.4MHz)

Date/Time: 2010-04-28 12:38:13
Test Laboratory: TCC Nokia
Type: RM-632; Serial: 004401/10/933781/2

Date/Time: 2010-04-28 13:25:11
Test Laboratory: TCC Nokia
Type: RM-632; Serial: 004401/10/933781/2

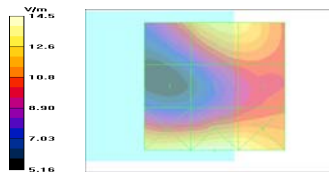
Communication System: WCDMA1900
Frequency: 1852.4 MHz; Duty Cycle: 1:1
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³
Phantom section: E Device Section

Communication System: WCDMA1900 (H3DV6)
Frequency: 1852.4 MHz; Duty Cycle: 1:1
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³
Phantom section: H Device Section

DASY4 Configuration:
- Probe: ER3DV6 - SN2309
- ConvF(1, 1, 1); Calibrated: 2009-10-27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1213; Calibrated: 2009-11-16
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

DASY4 Configuration:
- Probe: H3DV6 - SN6143
- ; Calibrated: 2009-10-23
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1213; Calibrated: 2009-11-16
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

E Scan - Low - measurement distance, sensor center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 13.3 V/m
Probe Modulation Factor = 0.600
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 12.8 V/m; Power Drift = -0.138 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)



Grid 1 11.6 M4	Grid 2 13.3 M4	Grid 3 13.1 M4
Grid 4 7.81 M4	Grid 5 10.3 M4	Grid 6 10.6 M4
Grid 7 14.1 M4	Grid 8 14.5 M4	Grid 9 13.9 M4

H Scan - Low - measurement distance, sensor center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.030 A/m
Probe Modulation Factor = 0.520
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 0.055 A/m; Power Drift = 0.073 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)



Grid 1 0.027 M4	Grid 2 0.025 M4	Grid 3 0.025 M4
Grid 4 0.029 M4	Grid 5 0.030 M4	Grid 6 0.030 M4
Grid 7 0.038 M4	Grid 8 0.034 M4	Grid 9 0.030 M4

MEASUREMENT DATA WCDMA1900, CHANNEL MIDDLE (1880MHz)

Date/Time: 2010-04-28 12:24:31
Test Laboratory: TCC Nokia
Type: RM-632; Serial: 004401/10/933781/2

Date/Time: 2010-04-28 13:04:40
Test Laboratory: TCC Nokia
Type: RM-632; Serial: 004401/10/933781/2

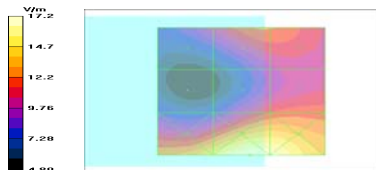
Communication System: WCDMA1900
Frequency: 1880 MHz; Duty Cycle: 1:1
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³
Phantom section: E Device Section

Communication System: WCDMA1900 (H3DV6)
Frequency: 1880 MHz; Duty Cycle: 1:1
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³
Phantom section: H Device Section

DASY4 Configuration:
- Probe: ER3DV6 - SN2309
- ConvF(1, 1, 1); Calibrated: 2009-10-27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1213; Calibrated: 2009-11-16
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

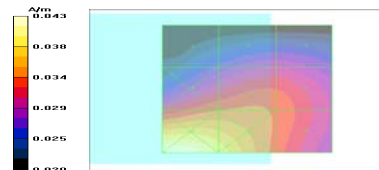
DASY4 Configuration:
- Probe: H3DV6 - SN6143
- ; Calibrated: 2009-10-23
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1213; Calibrated: 2009-11-16
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

E Scan -Middle - measurement distance, sensor center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 12.4 V/m
Probe Modulation Factor = 0.600
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 12.9 V/m; Power Drift = -0.305 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)



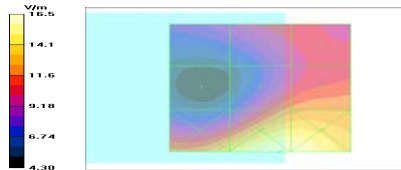
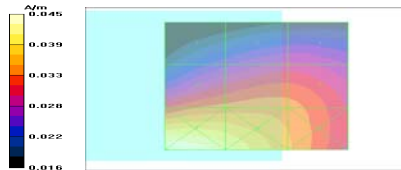
Grid 1	Grid 2	Grid 3
10.2	12.4	12.3
M4	M4	M4
Grid 4	Grid 5	Grid 6
8.22	11.5	11.9
M4	M4	M4
Grid 7	Grid 8	Grid 9
15.2	17.2	16.9
M4	M4	M4

H Scan - Middle - Measurement distance, sensor center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.034 A/m
Probe Modulation Factor = 0.520
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 0.071 A/m; Power Drift = -0.073 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)



Grid 1	Grid 2	Grid 3
0.027	0.029	0.029
M4	M4	M4
Grid 4	Grid 5	Grid 6
0.034	0.034	0.034
M4	M4	M4
Grid 7	Grid 8	Grid 9
0.043	0.040	0.034
M4	M4	M4

MEASUREMENT DATA WCDMA1900, CHANNEL HIGH (1907.6MHz)

Date/Time: 2010-04-28 12:30:26 Test Laboratory: TCC Nokia Type: RM-632; Serial: 004401/10/933781/2	Date/Time: 2010-04-28 13:15:43 Test Laboratory: TCC Nokia Type: RM-632; Serial: 004401/10/933781/2																		
Communication System: WCDMA1900 Frequency: 1907.6 MHz; Duty Cycle: 1:1 Medium: Air; Medium Notes: - Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³ Phantom section: E Device Section	Communication System: WCDMA1900 (H3DV6) Frequency: 1907.6 MHz; Duty Cycle: 1:1 Medium: Air; Medium Notes: - Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³ Phantom section: H Device Section																		
DASY4 Configuration: - Probe: ER3DV6 - SN2309 - ConvF(1, 1, 1); Calibrated: 2009-10-27 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1213; Calibrated: 2009-11-16 - Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: - - Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184	DASY4 Configuration: - Probe: H3DV6 - SN6143 - ; Calibrated: 2009-10-23 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1213; Calibrated: 2009-11-16 - Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: - - Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184																		
E Scan - High - measurement distance, sensor center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 12.4 V/m Probe Modulation Factor = 0.600 Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 14.0 V/m; Power Drift = -0.304 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)  <table><tr><td>Grid 1 9.11 M4</td><td>Grid 2 10.4 M4</td><td>Grid 3 10.5 M4</td></tr><tr><td>Grid 4 7.17 M4</td><td>Grid 5 11.9 M4</td><td>Grid 6 12.4 M4</td></tr><tr><td>Grid 7 14.0 M4</td><td>Grid 8 16.5 M4</td><td>Grid 9 16.2 M4</td></tr></table>	Grid 1 9.11 M4	Grid 2 10.4 M4	Grid 3 10.5 M4	Grid 4 7.17 M4	Grid 5 11.9 M4	Grid 6 12.4 M4	Grid 7 14.0 M4	Grid 8 16.5 M4	Grid 9 16.2 M4	H Scan - High - measurement distance, sensor center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.035 A/m Probe Modulation Factor = 0.520 Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 0.066 A/m; Power Drift = -0.078 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)  <table><tr><td>Grid 1 0.025 M4</td><td>Grid 2 0.028 M4</td><td>Grid 3 0.028 M4</td></tr><tr><td>Grid 4 0.034 M4</td><td>Grid 5 0.035 M4</td><td>Grid 6 0.034 M4</td></tr><tr><td>Grid 7 0.045 M4</td><td>Grid 8 0.042 M4</td><td>Grid 9 0.036 M4</td></tr></table>	Grid 1 0.025 M4	Grid 2 0.028 M4	Grid 3 0.028 M4	Grid 4 0.034 M4	Grid 5 0.035 M4	Grid 6 0.034 M4	Grid 7 0.045 M4	Grid 8 0.042 M4	Grid 9 0.036 M4
Grid 1 9.11 M4	Grid 2 10.4 M4	Grid 3 10.5 M4																	
Grid 4 7.17 M4	Grid 5 11.9 M4	Grid 6 12.4 M4																	
Grid 7 14.0 M4	Grid 8 16.5 M4	Grid 9 16.2 M4																	
Grid 1 0.025 M4	Grid 2 0.028 M4	Grid 3 0.028 M4																	
Grid 4 0.034 M4	Grid 5 0.035 M4	Grid 6 0.034 M4																	
Grid 7 0.045 M4	Grid 8 0.042 M4	Grid 9 0.036 M4																	

APPENDIX C: RELEVANT PAGES FROM PROBE CALIBRATION REPORT(S)



Accredited by the Swiss Accreditation Service (SAS)
 The Swiss Accreditation Service is one of the signatories to the EA
 Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

Client **Nokia Salo TCC**

Certificate No: **ER3-2309_Oct09**

CALIBRATION CERTIFICATE

Object **ER3DV6 - SN:2309**

Calibration procedure(s) **QA CAL-02.v5 and QA CAL-25.v2**
Calibration procedure for E-field probes optimized for close near field evaluations in air

Calibration date: **October 27, 2009**

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
 The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature $(22 \pm 3)^{\circ}\text{C}$ and humidity $< 70\%$.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4419B	GB41293874	1-Apr-09 (No. 217-01030)	Apr-10
Power sensor E4412A	MY41495277	1-Apr-09 (No. 217-01030)	Apr-10
Power sensor E4412A	MY41498087	1-Apr-09 (No. 217-01030)	Apr-10
Reference 3 dB Attenuator	SN: S5054 (3c)	31-Mar-09 (No. 217-01026)	Mar-10
Reference 20 dB Attenuator	SN: S5086 (20b)	31-Mar-09 (No. 217-01028)	Mar-10
Reference 30 dB Attenuator	SN: S5129 (30b)	31-Mar-09 (No. 217-01027)	Mar-10
Reference Probe ER3DV6	SN: 2328	3-Oct-09 (No. ER3-2328_Oct09)	Oct-10
DAE4	SN: 789	19-Dec-08 (No. DAE4-789_Dec08)	Dec-09

Secondary Standards	ID #	Check Date (in house)	Scheduled Check
RF generator HP 8648C	US3642U01700	4-Aug-99 (in house check Oct-09)	In house check: Oct-11
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-09)	In house check: Oct10

	Name	Function	Signature
Calibrated by:	Marcel Fehr	Laboratory Technician	

Approved by:	Katja Pokovic	Technical Manager	
--------------	---------------	-------------------	--

Issued: October 27, 2009

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.



Accredited by the Swiss Accreditation Service (SAS)

Accreditation No.: **SCS 108**

The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Client **Nokia Salo TCC**

Certificate No: **H3-6143_Oct09**

CALIBRATION CERTIFICATE

Object

H3DV6 - SN:6143

Calibration procedure(s)

QA CAL-03.v5 and QA CAL-25.v2
Calibration procedure for H-field probes optimized for close near field
evaluations in air

Calibration date:

October 23, 2009

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature $(22 \pm 3)^\circ\text{C}$ and humidity $< 70\%$.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4419B	GB41293874	1-Apr-09 (No. 217-01030)	Apr-10
Power sensor E4412A	MY41495277	1-Apr-09 (No. 217-01030)	Apr-10
Power sensor E4412A	MY41498087	1-Apr-09 (No. 217-01030)	Apr-10
Reference 3 dB Attenuator	SN: S5054 (3c)	31-Mar-09 (No. 217-01026)	Mar-10
Reference 20 dB Attenuator	SN: S5086 (20b)	31-Mar-09 (No. 217-01028)	Mar-10
Reference 30 dB Attenuator	SN: S5129 (30b)	31-Mar-09 (No. 217-01027)	Mar-10
Reference Probe H3DV6	SN: 6182	3-Oct-09 (No. H3-6182_Oct09)	Oct-10
DAE4	SN: 789	19-Dec-08 (No. DAE4-789_Dec08)	Dec-09

Secondary Standards	ID #	Check Date (in house)	Scheduled Check
RF generator HP 8648C	US3642U01700	4-Aug-99 (in house check Oct-09)	In house check: Oct-11
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-09)	In house check: Oct10

	Name	Function	Signature
Calibrated by:	Marcel Fehr	Laboratory Technician	

Approved by:	Katja Pokovic	Technical Manager	
--------------	---------------	-------------------	--

Issued: October 27, 2009

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

APPENDIX D: RELEVANT PAGES FROM DIPOLE VALIDATION KIT REPORT(S)



Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

Client **Nokia Salo TCC**

Certificate No: **CD835V3-1005_Nov08**

CALIBRATION CERTIFICATE

Object	CD835V3 - SN: 1005
Calibration procedure(s)	QA CAL-20.v4 Calibration procedure for dipoles in air
Calibration date:	November 11, 2008
Condition of the calibrated item	In Tolerance

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI)
All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter EPM-442A	GB37480704	08-Oct-08 (No. 217-00898)	Oct-09
Power sensor HP 8481A	US37292783	08-Oct-08 (No. 217-00898)	Oct-09
Probe ER3DV6	SN: 2336	31-Dec-07 (No. ER3-2336_Dec07)	Dec-08
Probe H3DV6	SN: 6065	31-Dec-07 (No. H3-6065_-Dec07)	Dec-08
DAE4	SN: 781	03-Oct-08 (No. DAE4-781_Oct08)	Oct-09
Secondary Standards	ID #	Check Date (in house)	Scheduled Check
Power meter EPM-4419B	GB42420191	11-May-05 (in house check Oct-07)	In house check: Oct-09
Power sensor HP 8482A	US37295597	11-May-05 (in house check Oct-07)	In house check: Oct-09
Power sensor HP 8482H	3318A09450	08-Jan-02 (in house check Oct-07)	In house check: Oct-09
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-08)	In house check: Oct-09
RF generator E4433B	MY 41310391	03-Nov-04 (in house check Oct-07)	In house check: Oct-09

	Name	Function	Signature
Calibrated by:	Claudio Leubler	Laboratory Technician	
Approved by:	Katja Pokovic	Technical Manager	

Issued: November 13, 2008

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

3.3.2 DASY4 H-field result

Date/Time: 11.11.2008 08:45:34

Test Laboratory: SPEAG Lab 2

H_CD835_1005_081111

DUT: HAC-Dipole 835 MHz; Type: D835V3; Serial: 1005

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 - SN6065; ; Calibrated: 31.12.2007
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 03.10.2008
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY4, V4.7 Build 71; Postprocessing SW: SEMCAD, V1.8 Build 184

H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.441 A/m

Probe Modulation Factor = 1.00

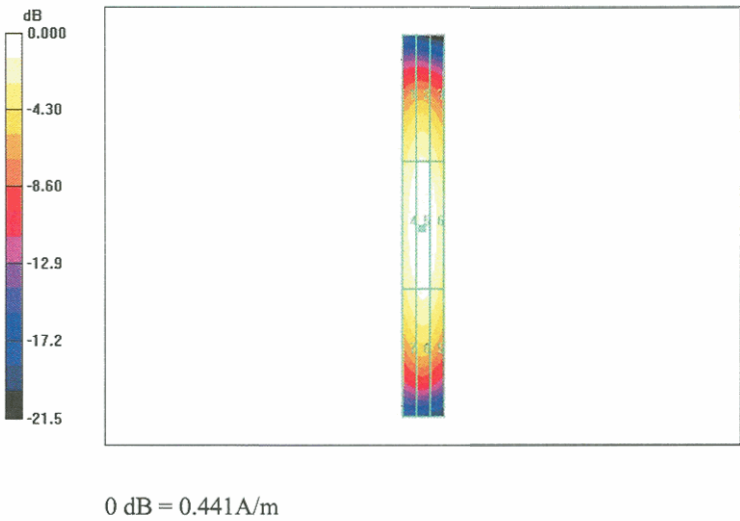
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.467 A/m; Power Drift = 0.006 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.370 M4	Grid 2 0.385 M4	Grid 3 0.358 M4
Grid 4 0.423 M4	Grid 5 0.441 M4	Grid 6 0.412 M4
Grid 7 0.376 M4	Grid 8 0.394 M4	Grid 9 0.368 M4



Test Laboratory: SPEAG Lab 2

E_CD835_1005_081111

DUT: HAC-Dipole 835 MHz; Type: D835V3; Serial: 1005

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 - SN2336; ConvF(1, 1, 1); Calibrated: 31.12.2007
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 03.10.2008
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY4, V4.7 Build 71; Postprocessing SW: SEMCAD, V1.8 Build 184

E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1):

Measurement grid: dx=5mm, dy=5mm

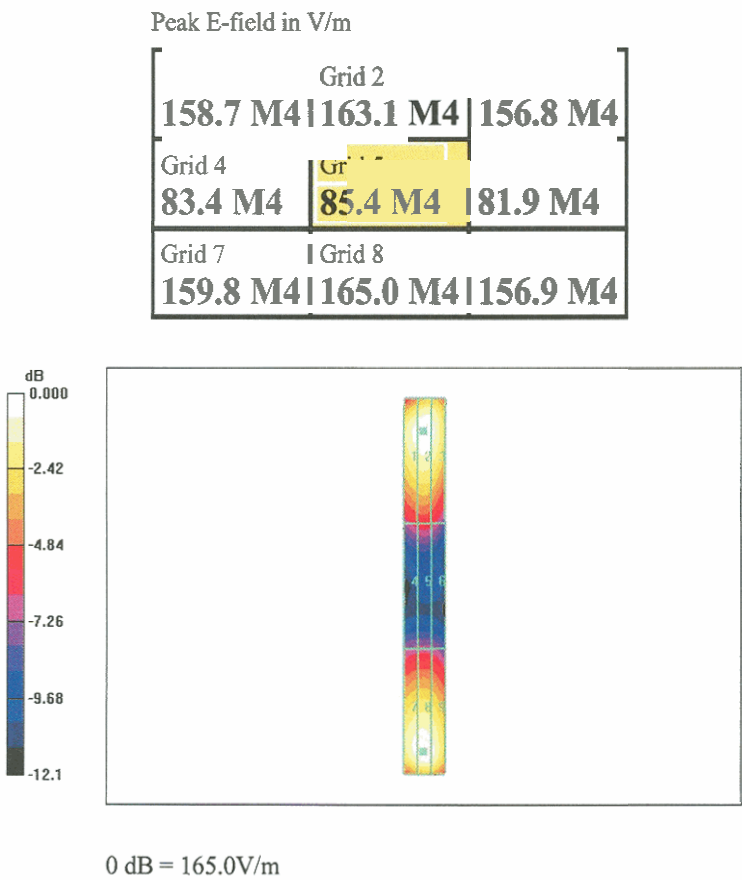
Maximum value of peak Total field = 165.0 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 107.1 V/m; Power Drift = -0.020 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)





Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

Client **Nokia Salo TCC**

Certificate No: **CD1880V3-1004_Nov08**

CALIBRATION CERTIFICATE

Object	CD1880V3 - SN: 1004
Calibration procedure(s)	QA CAL-20.v4 Calibration procedure for dipoles in air
Calibration date:	November 11, 2008
Condition of the calibrated item	In Tolerance

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter EPM-442A	GB37480704	08-Oct-08 (No. 217-00898)	Oct-09
Power sensor HP 8481A	US37292783	08-Oct-08 (No. 217-00898)	Oct-09
Probe ER3DV6	SN: 2336	31-Dec-07 (No. ER3-2336_Dec07)	Dec-08
Probe H3DV6	SN: 6065	31-Dec-07 (No. H3-6065_-Dec07)	Dec-08
DAE4	SN 781	03-Oct-08 (No. DAE4-781_Oct08)	Oct-09

Secondary Standards	ID #	Check Date (in house)	Scheduled Check
Power meter EPM-4419B	GB42420191	11-May-05 (in house check Oct-07)	In house check: Oct-09
Power sensor HP 8482A	US37295597	11-May-05 (in house check Oct-07)	In house check: Oct-09
Power sensor HP 8482H	3318A09450	08-Jan-02 (in house check Oct-07)	In house check: Oct-09
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-08)	In house check: Oct-09
RF generator E4433B	MY 41310391	22-Nov-04 (in house check Oct-07)	In house check: Oct-09

Calibrated by:	Name	Function	Signature
	Claudio Leubler	Laboratory Technician	
Approved by:	Katja Pokovic	Technical Manager	

Issued: November 13, 2008

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

Test Laboratory: SPEAG Lab 2

H_CD1880_1004_081111

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1004

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 - SN6065; ; Calibrated: 31.12.2007
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 03.10.2008
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY4, V4.7 Build 71; Postprocessing SW: SEMCAD, V1.8 Build 184

H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm 2/Hearing Aid

Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.461 A/m

Probe Modulation Factor = 1.00

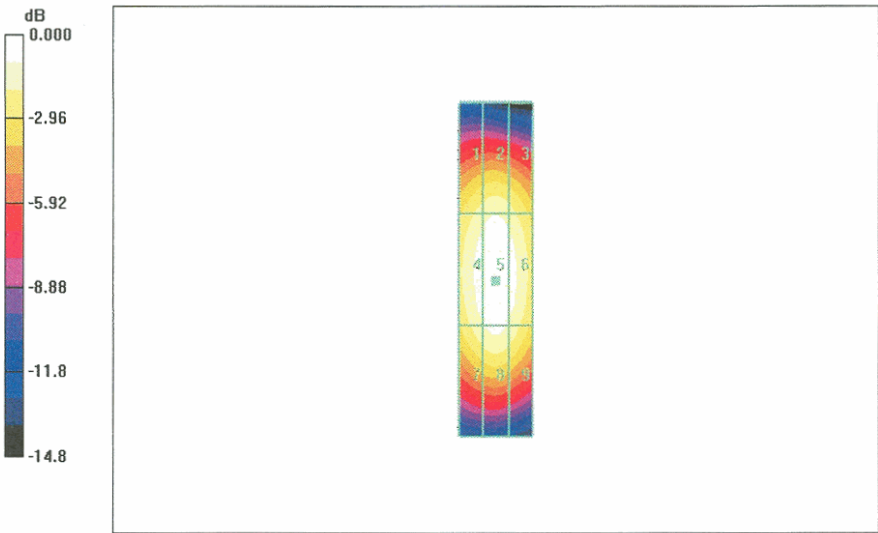
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.488 A/m; Power Drift = -0.018 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.394 M2	Grid 2 0.410 M2	Grid 3 0.390 M2
Grid 4 0.442 M2	Grid 5 0.461 M2	Grid 6 0.438 M2
Grid 7 0.409 M2	Grid 8 0.430 M2	Grid 9 0.406 M2



0 dB = 0.461A/m

3.3.2 DASY4 E-Field Result

Date/Time: 11.11.2008 12:54:31

Test Laboratory: SPEAG Lab 2

E_CD1880_1004_081111

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1004

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 - SN2336; ConvF(1, 1, 1); Calibrated: 31.12.2007
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 03.10.2008
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY4, V4.7 Build 71; Postprocessing SW: SEMCAD, V1.8 Build 184

E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 138.8 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 157.2 V/m; Power Drift = -0.005 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak E-field in V/m

131.1 M2 136.9 M2 133.9 M2		
Grid 4 89.6 M3	5 92.1 M3	Grid 6 88.3 M3
Grid 7 133.8 M2	Grid 8 138.8 M2	Grid 9 133.2 M2

